NSN 5961-00-262-0798

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View Online at https://aerobasegroup.com/nsn/5961-00-262-0798 **Inclosure Material:** Metal **Overall Length:** 0.085 inches **Terminal Length:** 1.000 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-46 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 collector to base voltage/static/emitter open and 12.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current and 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 360.0 milliwatts large-signal input power, common-emitter preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Precious Material And Location:** Terminals gold **Precious Material:** Gold **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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